Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S2	4	(("20010006827") or ("20020011205")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/17 16:17
S3	722	(438/29).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/16 10:04
S4	0	S3 and ((mov\$3 reciprocat\$3) same ((substrate semiconduct\$3) and (evaporat\$3 near5 (souce cell))))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 10:09
S5	141	S3 and ((mov\$3 reciprocat\$3) same (substrate semiconduct\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:50
S6	99	S3 and (EL electro near3 luminescence)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 16:06
S7	0	("2004/0077113").URPN.	USPAT	OR	ON	2005/08/16 10:19
S8	0	("2004/0009303").URPN.	USPAT	OR	ON	2005/08/16 10:20

, Sa	an	("20010001050" "20020041302"	US-PGPUB;	OR	ON	2005/08/16 12:58
S9	90	("20010001050" "20020041302" "20020041926" "20020136823" "20020155215" "20030054186" "4356429" "4530750" "4539507" "4720432" "4769292" "4885211" "4950950" "4975338" "5003221" "5047687" "5059861" "5059862" "5061617" "5073446" "5107175" "5124204" "5151629" "5189405" "5217700" "5247190" "5270267" "5294869" "5294870" "5338364" "5399502" "5438241" "5482896" "5496597" "5530269" "5552668" "5641991" "5643826" "5674304" "5680165" "5680185" "56893956" "5747930" "5757126" "5771562" "5811177" "5824374" "5839456" "5923962" "5929487" "5923962" "5929487" "5923962" "5929487" "5952708" "5952778" "5962962" "6115090" "6129602" "6146225" "6150187" "6150668" "6169293" "6194837" "6251712" "6268631" "6258578" "6268842" "6239470" "6251712" "6268631" "6278132" "6268634" "6283578" "6316810" "6413645" "6441468" "6451636" "6461885" "6575800" "6619334" "6667188").PN.	US-PGPUB; USPAT; USOCR	OK .	UN	
S10	0	("6810919").URPN.	USPAT	OR	ON	2005/08/16 12:58
S11	4	("20020041302" "6451636" "6619334" "6667188").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/08/16 12:59
S12	287	(438/69).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/16 14:06
S13	113	S12 and (apparatus reactor same (vapor near3 deposition))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 16:05

S14	170	(438/82).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/16 14:50
S15	4	("2001/0006827").URPN.	USPAT	OR	ON	2005/08/16 15:41
S16	4	("2001/0006827").URPN.	USPAT	OR	ON	2005/08/16 15:41
S17	567	(438/99).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/16 16:04
S18	567	(438/99).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/16 16:04
S19	182	S18 and (vapor near3 deposition)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:18
S20	104	S18 and (EL (electro near3 luminescence))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:18
S21	1638	(438/680).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/17 16:17
S22	771	S21 and (vapor near3 deposition)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:54
S23	7	S22 and (EL (electro near3 luminescence))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:54

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S24	8	S21 and (EL (electro near3 luminescence))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:25
S25	3	("2001093667").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/17 16:31
S26	1364	S21 and ((uniform even flat) near5 surface film)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:55
S27	670	S22 and ((uniform even flat) near5 surface film)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:32
S28	2	S22 and ((mov\$3 reciprocat\$3) near5 ((substrate semiconduct\$3) and (source cell evaporat\$3)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:56
S29	768634	EL (electro near3 luminescence)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:54
S30	6901	S29 and (vapor near3 deposition)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:54
S31	2550	S30 and ((uniform even flat) near5 (surface film))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 16:55

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S32	14	S31 and ((mov\$3 reciprocat\$3) near5 ((substrate semiconduct\$3) and (evaporat\$3 near4 source)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 17:02
S33	389	S31 and ((mov\$3 reciprocat\$3) near5 (substrate semiconduct\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 18:25
S34	14	S33 and ((mov\$3 reciprocat\$3) near5 (evaporat\$3 near4 source))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 17:22
S35	24	S31 and ((mov\$3 reciprocat\$3 direction) near5 (evaporat\$3 near4 source))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 17:23
S36	23	S35 and ((mov\$3 reciprocat\$3 direction) near5 (substrate semiconduct\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 17:24
S37	22	S35 and ((mov\$3 reciprocat\$3 direction) near3 (substrate semiconduct\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/17 17:24
S38	0	("2004/0031442").URPN.	USPAT	OR	ON	2005/08/18 12:41
S39	18	(("2435997") or ("3931490") or ("4951601") or ("6049167") or ("6132280") or ("20010006827") or ("20020197418")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/18 12:49
S40	2	("20040031442").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/18 12:54

S41	4	(("20020187265") or ("20020197418")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/18 12:59
S42	2	("20040040504").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/18 12:59
S43	0	("2004/0009303").URPN.	USPAT	OR	ON	2005/08/18 13:15